

Description

The AP22802 is a single channel current-limited integrated high-side power switch optimized for Universal Serial Bus (USB) and other hot-swap applications. The family of devices complies with USB standards and is available with both polarities of Enable input.

The device has fast short-circuit response time for improved overall system robustness, and has an integrated output discharge function to ensure completely controlled discharging of the output voltage capacitor. They provide a complete protection solution for applications subject to heavy capacitive loads and the prospect of short circuit, and offer reverse current blocking, over-current, over-temperature and short-circuit protection, as well as controlled rise time and under-voltage lockout functionality. A 6ms deglitch capability on the open-drain Flag output prevents false over-current reporting and does not require any external components.

The AP22802 is available in a standard Green SOT25 and RoHS compliant.

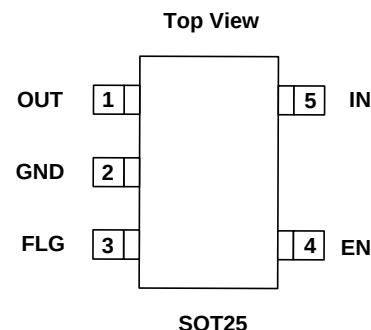
Features

- Integrated Single Channel Load Switch
- Protection
 - Over Current with Auto Recovery
 - Short Circuit with Auto Recovery
 - Over temperature with Auto Recovery
- Small Form Factor Packages
 - SOT25
 - footprint of just 9mm²
- Thermally Efficient Low Profile Package
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. “Green” Device (Note 3)**
- UL Recognized, File Number E322375
- IEC60950-1 CB Scheme Certified

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

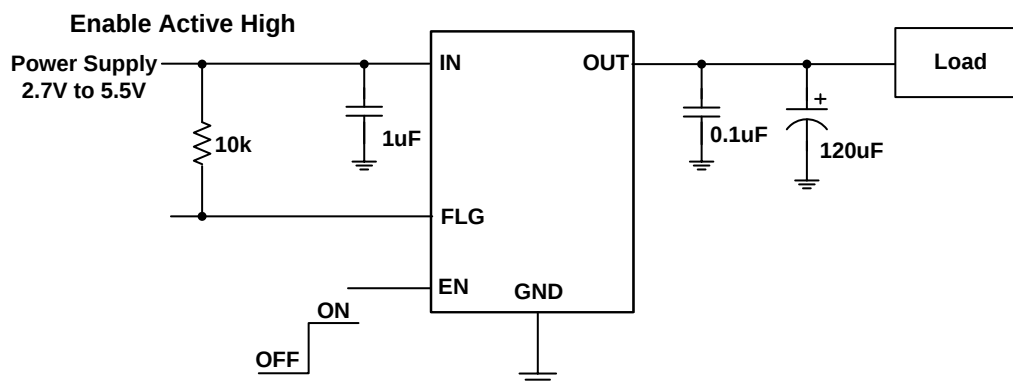
Pin Assignments



Applications

- Integrated Load Switches in Ultrabook PC's
- Power Up/Down Sequencing in Ultrabook PC's
- Notebook
- Netbook
- Set-Top Boxes
- SSD (Solid State Drives)
- Consumer Electronics
- Tablet PC
- Telecom Systems

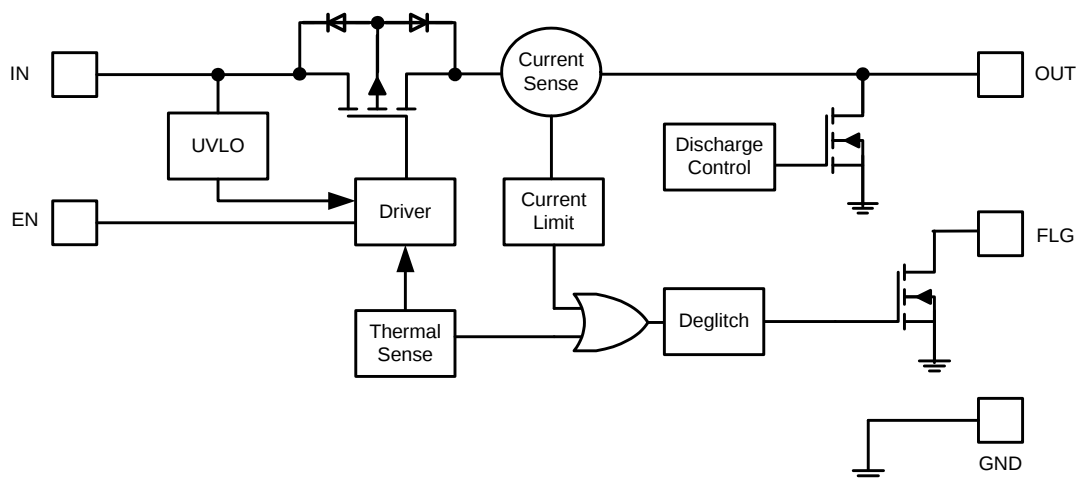
Typical Applications Circuit



Pin Descriptions

Pin Number	Pin Name	Function
1	OUT	Voltage Output Pin
2	GND	Ground Pin of the Circuitry
3	FLG	Over Current and Over temperature fault report ; Open-Drain flag is active low when triggered.
4	EN	Enable Input. AP22802A: Active High AP22802B: Active Low
5	IN	Voltage Input Pin

Functional Block Diagram



Absolute Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.) (Note 4)

Symbol	Parameter		Ratings	Units
ESD HBM	Human Body ESD Protection		2000	V
ESD MM	Machine Model ESD Protection		200	V
V_{IN}	Input Voltage		-0.3 to 5.7	V
V_{OUT}	Output Voltage		-0.3 to ($V_{IN} + 0.3$)	V
V_{EN}	Enable Voltage		-0.3 to ($V_{IN} + 0.3$)	V
I_L	Load Current		Internal Limited	A
$T_{J(max)}$	Maximum Junction Temperature		150	$^\circ\text{C}$
T_{ST}	Storage Temperature		-65 to +150	$^\circ\text{C}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	SOT25	240	$^\circ\text{C/W}$
$R_{\theta CC}$	Thermal Resistance, Junction to Case	SOT25	130	$^\circ\text{C/W}$

Note: 4. Stresses greater than the 'Absolute Maximum Ratings' specified above may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.

Recommended Operating Conditions (Note 5)

Symbol	Parameter	Min	Max	Unit
V _{IN}	Input voltage	2.7	5.5	V
I _{OUT}	Output Current	0	2	A
V _{IL}	EN Input Logic Low Voltage	0	0.5	V
V _{IH}	EN Input Logic High Voltage	1.5	V _{IN}	V
T _A	Operating Ambient Temperature	-40	+85	°C

Electrical Characteristics (V_{IN}=5V @ T_A = +25°C, C_{IN} = 1μF, C_L = 100nF, unless otherwise specified.)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V _{UVLO}	Input UVLO	V _{IN} rising	1.6	2.0	2.4	V
ΔV _{UVLO}	Input UVLO Hysteresis	V _{IN} decreasing		75		mV
I _{SHDN}	Input Shutdown Current	Disabled, OUT = open		0.1	1	μA
I _Q	Input Quiescent Current	Enabled, OUT = open		50		μA
I _{LEAK}	Input Leakage Current	Disabled, OUT grounded		0.1	1	μA
I _{REV}	Reverse Leakage Current	Disabled, V _{IN} = 0V, V _{OUT} = 5V, I _{REV} at V _{IN}		0.01	1	μA
R _{DS(ON)}	Switch On-Resistance	V _{IN} = 5V, I _{OUT} = 2.0A T _A = +25°C		50		mΩ
		V _{IN} = 3.3V, I _{OUT} = 2.0A T _A = +25°C		60		
I _{LIMIT}	Over Load Current Limit (Note 6)	V _{IN} = 5V, V _{OUT} = 4.5V		2.7	3.2	A
I _{SHORT}	Short-Circuit Current Limit	Enabled into short circuit		1.65		A
T _{SHORT}	Short-Circuit Response Time	V _{IN} = 5 V, No load Figure 1		0.7		μs
V _{IL}	EN Input Logic Low Voltage	V _{IN} = 2.7V to 5.5V			0.5	V
V _{IH}	EN Input Logic High Voltage	V _{IN} = 2.7V to 5.5V	1.5			V
I _{LEAK-EN}	EN Input Leakage	V _{IN} = 5V, V _{EN} = 0V and 5.5V		0.01	1	μA
I _{LEAK-O}	Output Leakage Current	Disabled, V _{OUT} = 0V		0.5	1	μA
T _{D(ON)}	Output Turn-On Delay Time	C _L = 4.7μF, R _{LOAD} = 10Ω @ V _{IN} = 3.3V Figure 2		1.7		ms
T _R	Output Turn-On Rise Time	C _L = 4.7μF, R _{LOAD} = 10Ω @ V _{IN} = 3.3V Figure 2	1.0	2.1	3.5	ms
T _{D(OFF)}	Output Turn-Off Delay Time	C _L = 4.7μF, R _{LOAD} = 10Ω @ V _{IN} = 3.3V Figure 2		0.2		ms
T _F	Output Turn-Off Fall Time	C _L = 4.7μF, R _{LOAD} = 100Ω @ V _{IN} = 3.3V Figure 2		0.65		ms
R _{FLG}	FLG output FET On-Resistance	I _{FLG} = 10mA		40	60	Ω
I _{FOH}	FLG Off Current	V _{FLG} = 5V		0.01	1	μA
T _{Blank}	FLG Blanking Time	Assertion or deassertion due to overcurrent and over-temperature condition	2	6	13	ms
T _{DIS}	Discharge Time	C _L = 1μF, V _{IN} = 5V, disabled to V _{OUT} < 0.5V		0.4		ms
R _{DIS}	Discharge Resistance	V _{IN} = 5V, disabled, I _{OUT} = 1mA		90		Ω
T _{SHDN}	Thermal Shutdown Threshold	Enabled		140		°C
T _{HYS}	Thermal Shutdown Hysteresis			15		°C

Note: 5. Refer to the typical application circuit

Typical Performance Characteristics

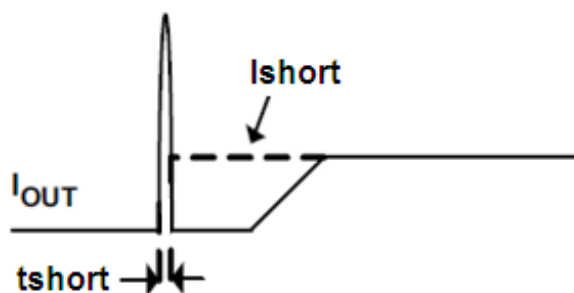


Figure 1 Response Time to Short Circuit Waveform

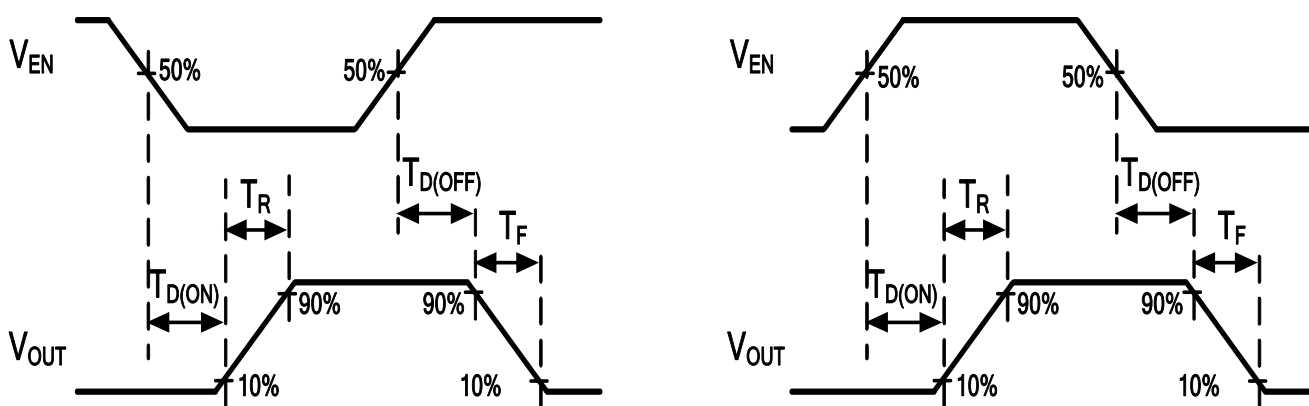
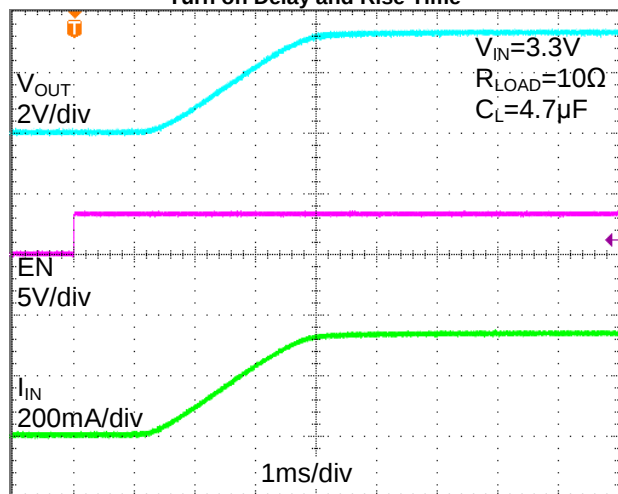


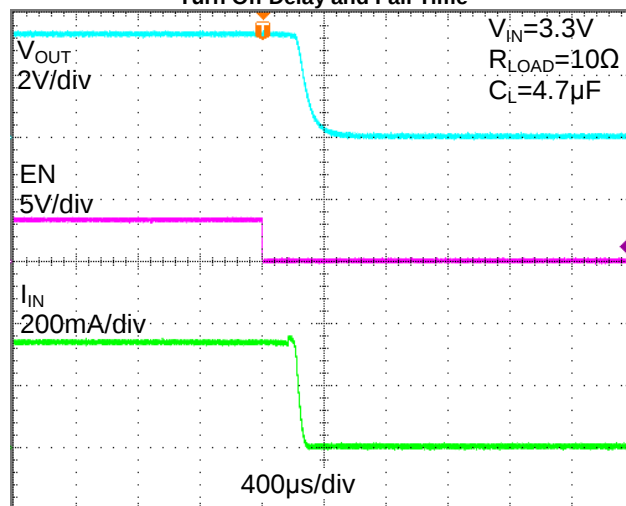
Figure 2 Voltage Waveforms: AP22802 (left), AP22802 (right)

Typical Performance Characteristics (cont.) ($T_A = +25^\circ\text{C}$, $V_{IN} = 5\text{V}$, $C_{IN} = 1\mu\text{F}$, $C_L = 0.1\mu\text{F}$, unless otherwise specified.)

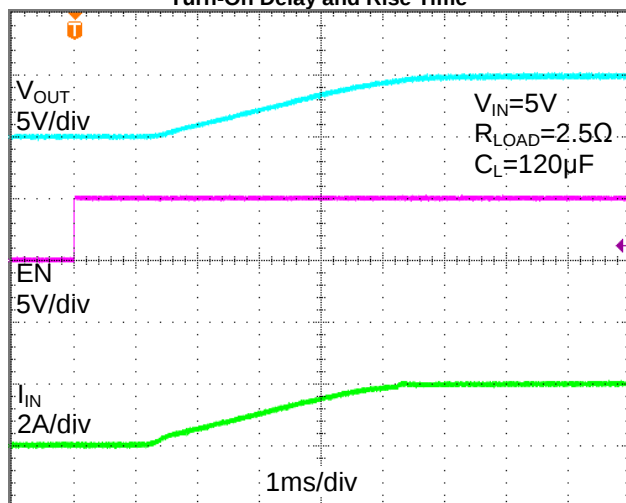
Turn on Delay and Rise Time



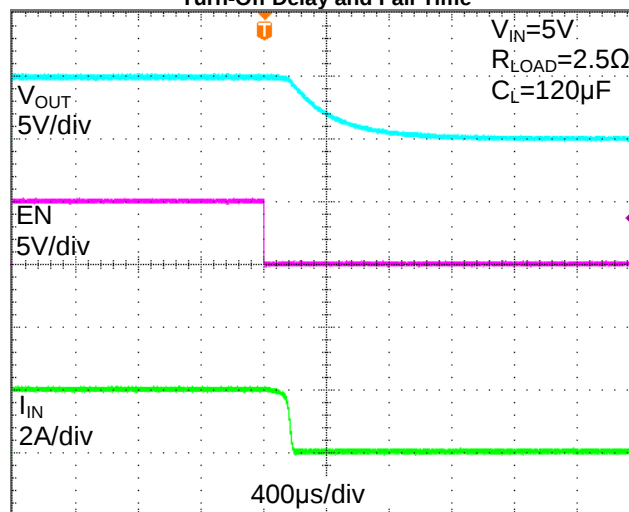
Turn Off Delay and Fall Time



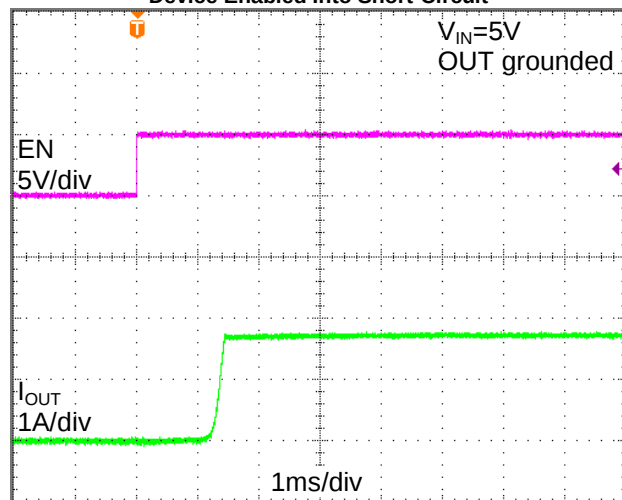
Turn-On Delay and Rise Time



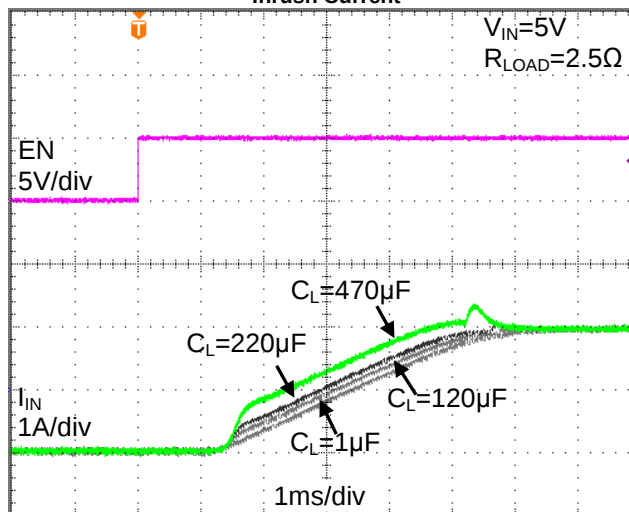
Turn-Off Delay and Fall Time



Device Enabled Into Short-Circuit

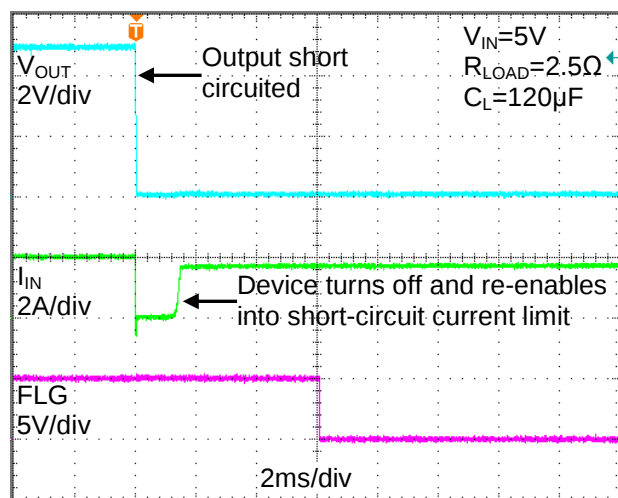


Inrush Current

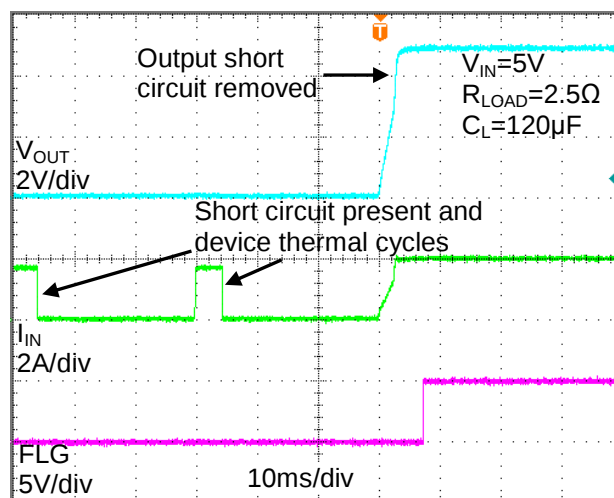


Typical Performance Characteristics (cont.) ($T_A = +25^\circ\text{C}$, $V_{IN} = 5\text{V}$, $C_{IN} = 1\mu\text{F}$, $C_L = 0.1\mu\text{F}$, unless otherwise specified.)

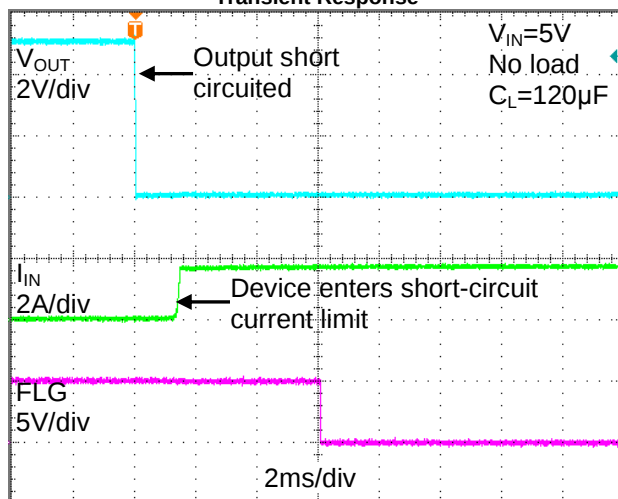
**Full-Load to Short-Circuit
Transient Response**



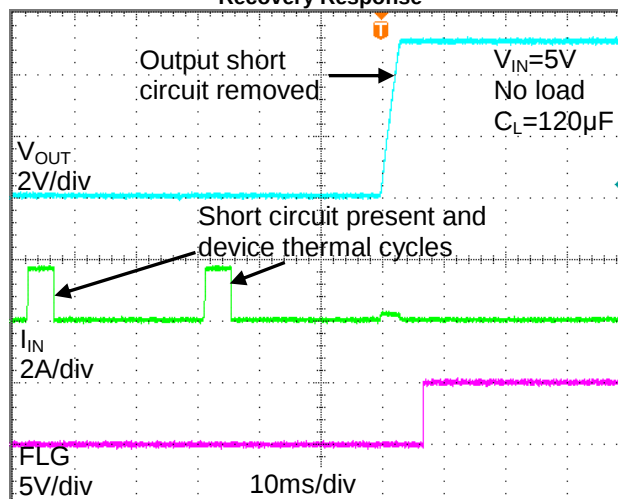
**Short-Circuit to Full-Load
Recovery Response**



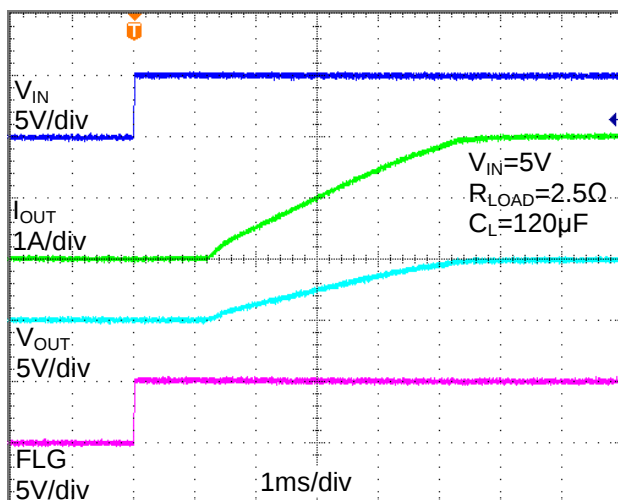
**No-Load to Short-Circuit
Transient Response**



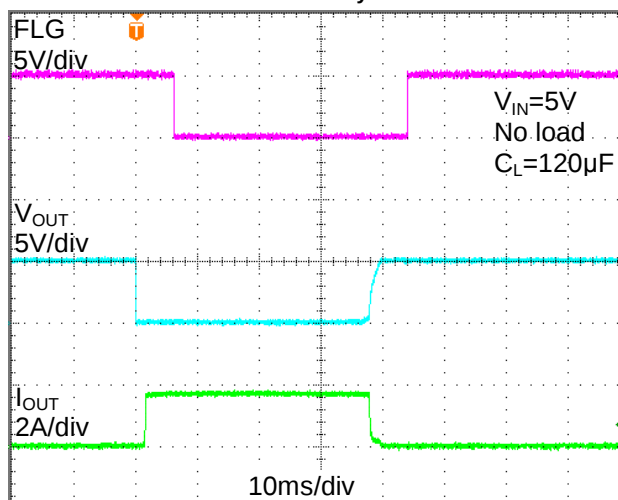
**Short-Circuit to No-Load
Recovery Response**



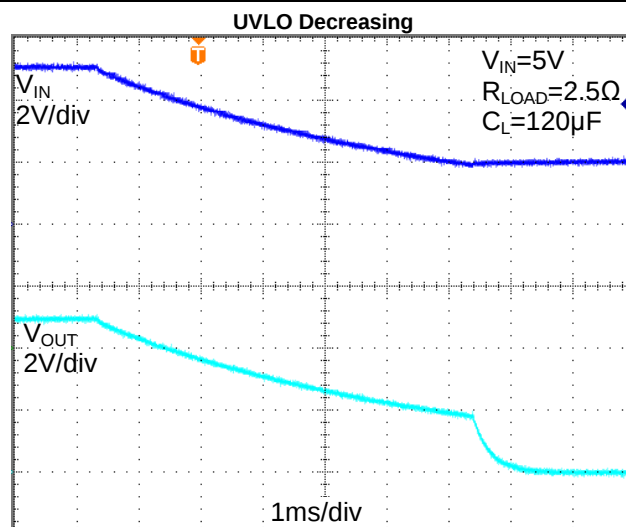
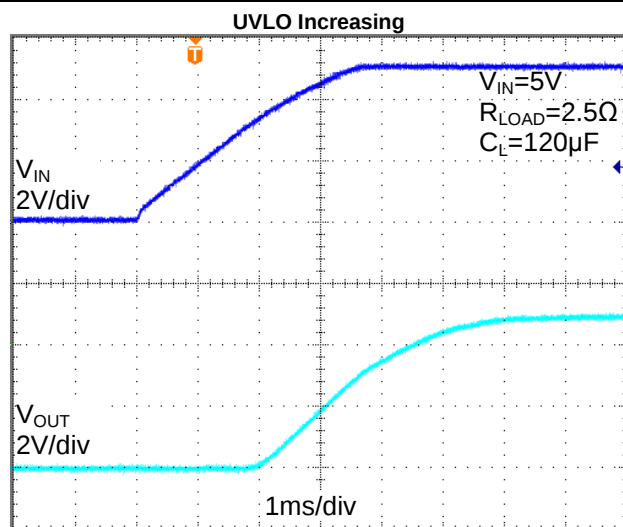
Power ON



**Short-Circuit with Blanking Time and
Recovery**

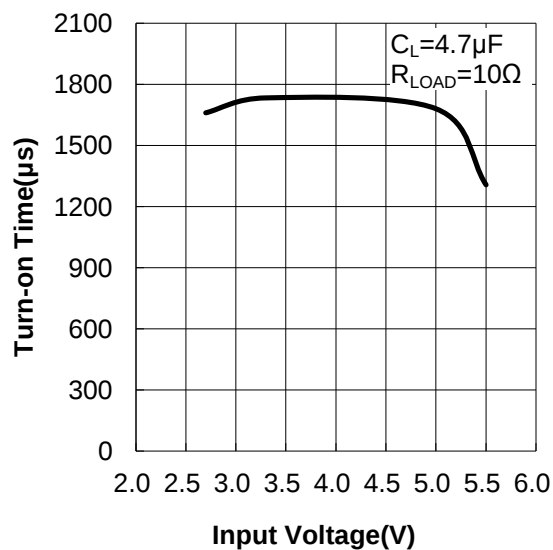


Typical Performance Characteristics (cont.) ($T_A = +25^\circ\text{C}$, $V_{IN} = 5\text{V}$, $C_{IN} = 1\mu\text{F}$, $C_L = 0.1\mu\text{F}$, unless otherwise specified.)

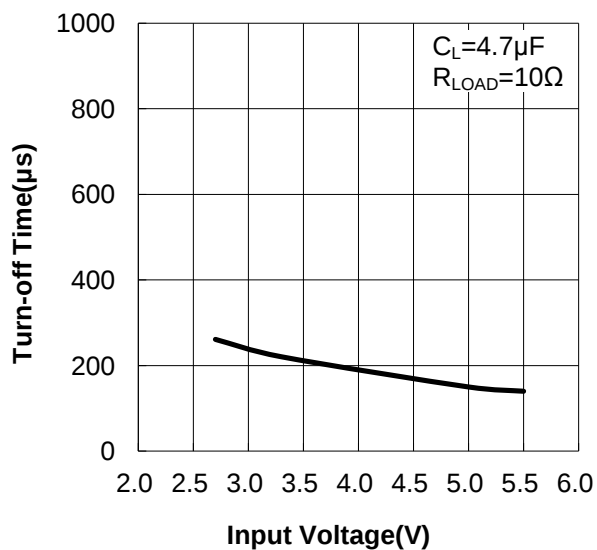


Typical Performance Characteristics (cont.) ($T_A = +25^\circ\text{C}$, $V_{IN} = 5\text{V}$, $C_{IN} = 1\mu\text{F}$, $C_L = 0.1\mu\text{F}$, unless otherwise specified.)

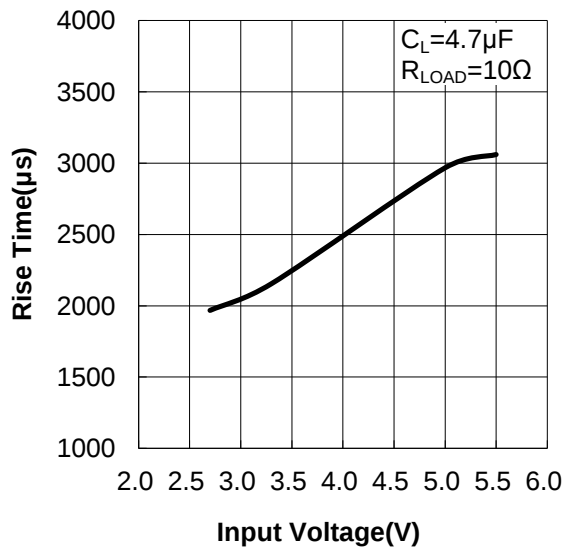
Turn-on Time vs. Input Voltage



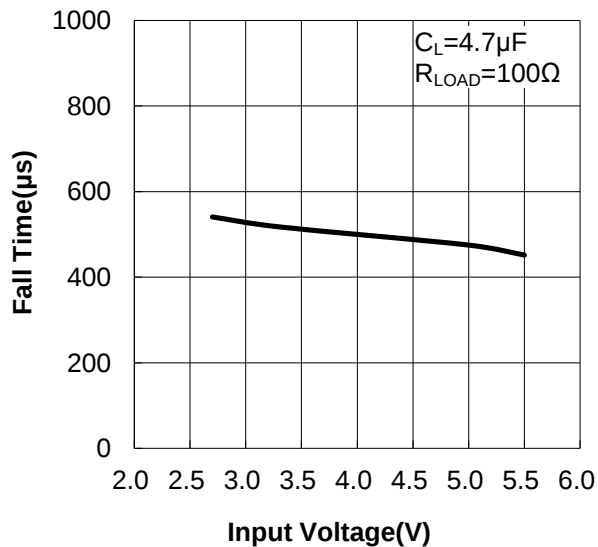
Turn-off Time vs. Input Voltage



Rise Time vs. Input Voltage

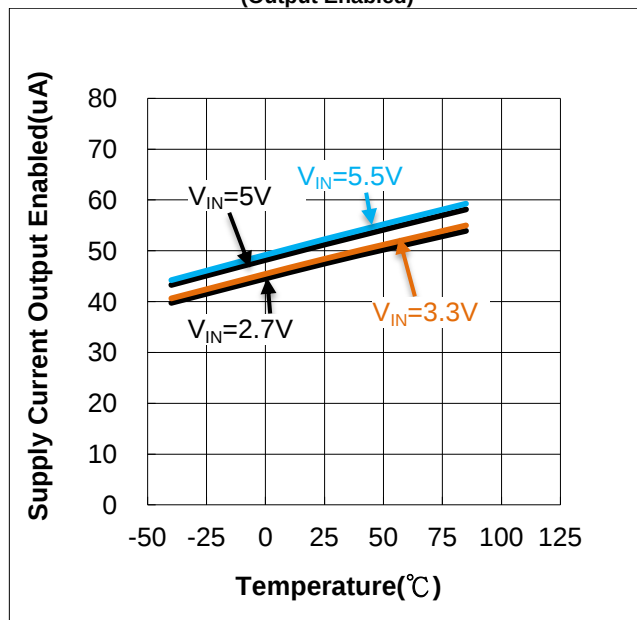


Fall Time vs. Input Voltage

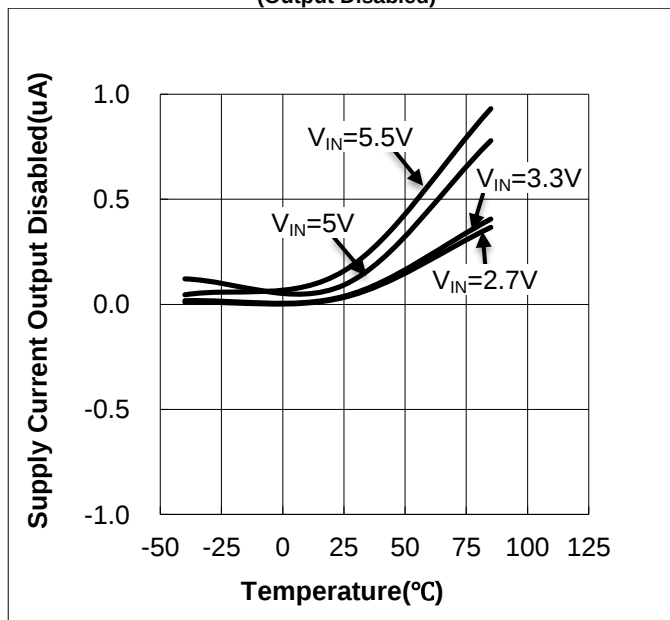


Typical Performance Characteristics (cont.) ($T_A = +25^\circ\text{C}$, $V_{IN} = 5\text{V}$, $C_{IN} = 1\mu\text{F}$, $C_L = 0.1\mu\text{F}$, unless otherwise specified.)

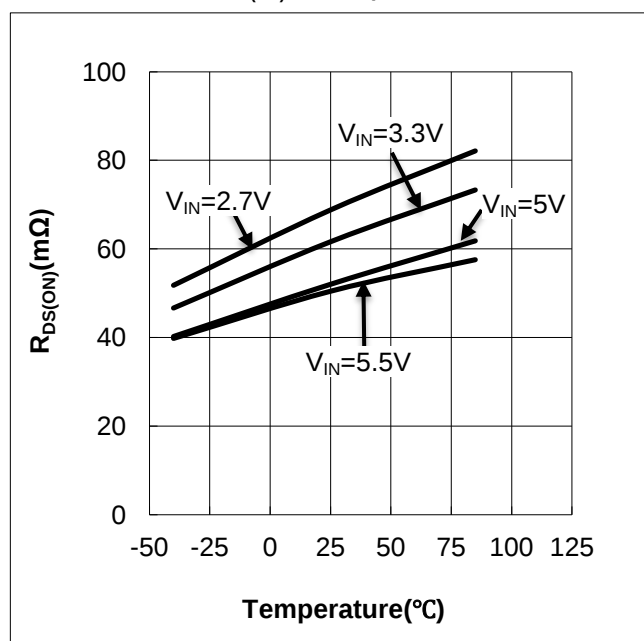
**Supply Current vs. Temperature
(Output Enabled)**



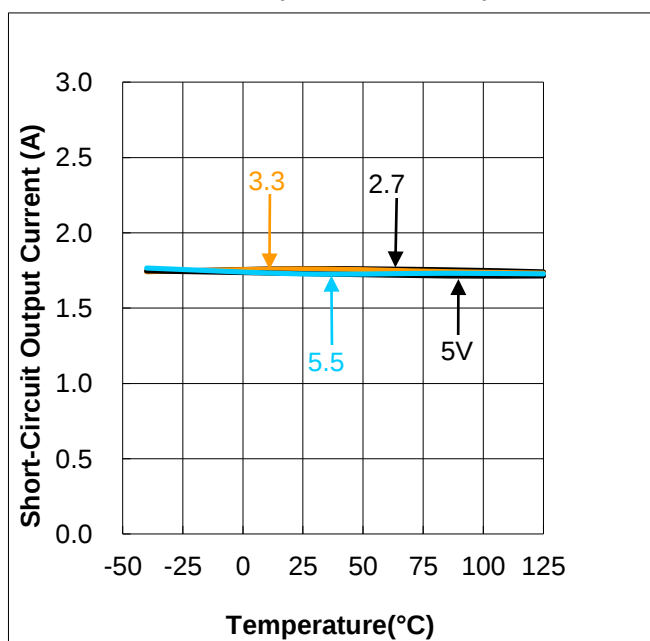
**Supply Current vs. Temperature
(Output Disabled)**



$R_{DS(ON)}$ vs. Temperature

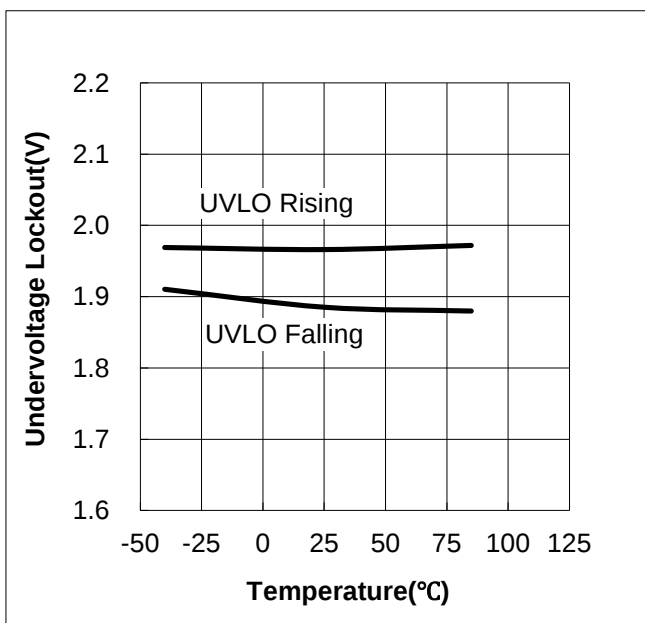


Short-Circuit Output Current vs. Temperature

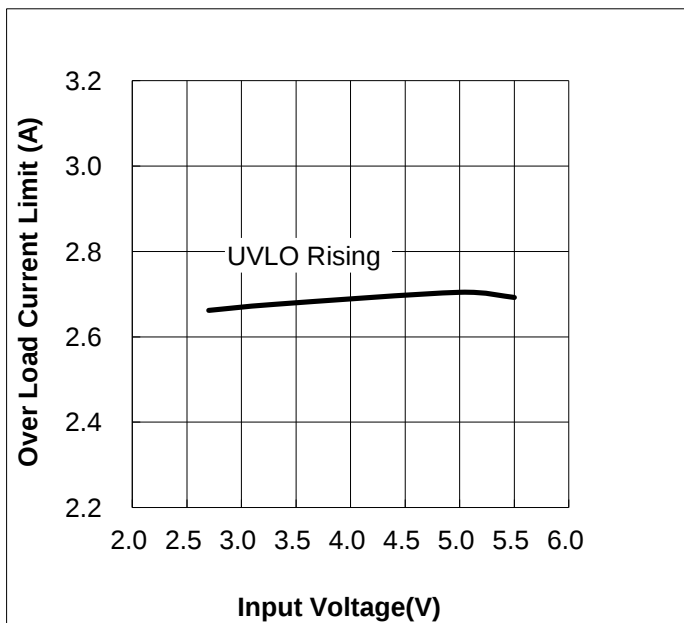


Typical Performance Characteristics (cont.) ($T_A = +25^\circ\text{C}$, $V_{IN} = 5\text{V}$, $C_{IN} = 1\mu\text{F}$, $C_L = 0.1\mu\text{F}$, unless otherwise specified.)

Under voltage Lockout vs. Temperature



Over Load Current Limit vs. Input Voltage



Application Information

Power Supply Considerations

A 1- μ F X7R or X5R ceramic bypass capacitor between IN and GND, close to the device, is recommended. Placing a high-value capacitor (10- μ F minimum) on both input and output pins is recommended when the output transient load is heavy. This precaution reduces power-supply transients that may cause ringing on the input. Additionally, bypassing the output with a 0.01- μ F to 0.1- μ F ceramic capacitor improves the immunity of the device to short-circuit transients.

FLG Response

When an over-current or over-temperature shutdown condition is encountered, the FLG open-drain output goes active low after a nominal 6-ms deglitch timeout. The FLG output remains low until both over-current and over-temperature conditions are removed. Connecting a heavy capacitive load to the output of the device can cause a momentary over-current condition, which does not trigger the FLG due to the 6-ms deglitch timeout. The AP22802 is designed to eliminate false over-current reporting without the need of external components to remove unwanted pulses.

Over-Current and Short Circuit Protection

An internal sensing FET is employed to check for over-current conditions. Unlike current-sense resistors, sense FETs do not increase the series resistance of the current path. When an overcurrent condition is detected, the device maintains a constant output current and reduces the output voltage accordingly. Complete shutdown occurs only if the fault stays long enough to activate thermal limiting.

Three possible overload conditions can occur. In the first condition, the output has been shorted to GND before the device is enabled or before VIN has been applied. The AP22802 senses the short circuit and immediately clamps output current to a certain safe level.

In the second condition, an output short or an overload occurs while the device is enabled. At the instance the overload occurs, higher current may flow for a very short period of time before the current limit function can react. After the current limit function has tripped, the device switches into current limiting mode and the current is clamped at I_{LIMIT} , or I_{SHORT} .

In the third condition, the load has been gradually increased beyond the recommended operating current. The current is permitted to rise until the current-limit threshold (I_{TRIG}) is reached or until the thermal limit of the device is exceeded. The AP22802 is capable of delivering current up to the current-limit threshold without damaging the device. Once the threshold has been reached, the device switches into its current limiting mode and is set at I_{LIMIT} .

Thermal Protection

Thermal protection prevents the IC from damage when heavy-overload or short-circuit faults are present for extended periods of time. The AP22802 implements a thermal sensing to monitor the operating junction temperature of the power distribution switch. Once the die temperature rises to approximately 140°C due to excessive power dissipation in an over-current or short-circuit condition the internal thermal sense circuitry turns the power switch off, thus preventing the power switch from damage. Hysteresis is built into the thermal sense circuit allowing the device to cool down approximately 15°C before the switch turns back on. The switch continues to cycle in this manner until the load fault or input power is removed. The FLG open-drain output is asserted when an over-temperature shutdown or over-current occurs with 6-ms deglitch.

ON/OFF Input Operator

The EN input allows the output current to be switched on and off using a GPIO compatible input. The high signal (switch on) should be at least 1.5V, and the low signal (switch off) no higher than 0.5V. This pin should NOT be left floating. It is advisable to hold the EN signal low when applying or removing power.

Under-voltage Lockout (UVLO)

Under-voltage lockout function (UVLO) keeps the internal power switch from being turned on until the power supply has reached at least 2V, even if the switch is enabled. Whenever the input voltage falls below approximately 2V, the power switch is quickly turned off. This facilitates the design of hot-insertion systems where it is not possible to turn off the power switch before input power is removed.

Discharge Function

The discharge function of the device is active when enable is disabled or de-asserted. The discharge function with the N-MOS power switch implementation is activated and offers a resistive discharge path for the external storage capacitor. This is designed for discharging any residue of the output voltage when either no external output resistance or load resistance is present at the output.

Application Information (cont.)

Power Dissipation and Junction Temperature

The low on-resistance of the internal MOSFET allows the small surface-mount packages to pass large current. Using the maximum operating ambient temperature (T_A) and $R_{DS(ON)}$, the power dissipation can be calculated by:

$$P_D = R_{DS(ON)} \times I^2$$

Finally, calculate the junction temperature:

$$T_J = P_D \times R_{\theta JA} + T_A$$

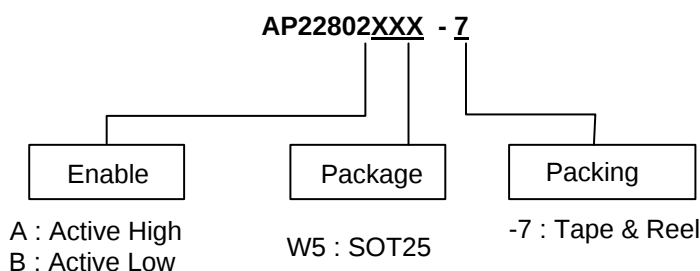
Where:

T_A = Ambient temperature °C

$R_{\theta JA}$ = Thermal resistance

P_D = Total power dissipation

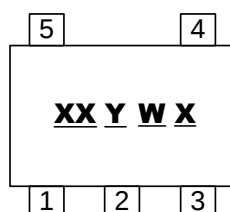
Ordering Information



Part Number	Package Code	Packaging	13" Tape and Reel	
			Quantity	Part Number Suffix
AP22802AW5-7	W5	SOT25	3000/Tape & Reel	-7
AP22802BW5-7	W5	SOT25	3000/Tape & Reel	-7

Marking Information

(Top View)

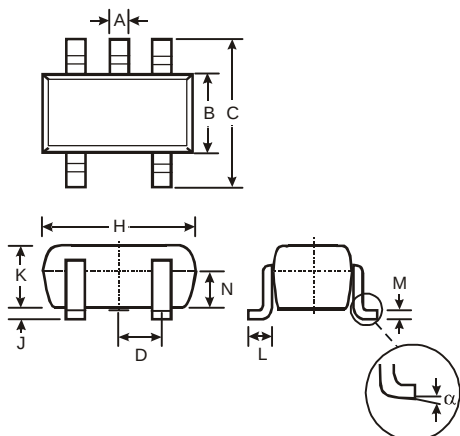


XX : Identification code
Y : Year 0~9
W : Week : A~Z : 1~26 week;
 a~z : 27~52 week; z represents
 52 and 53 week
X : A~Z : Green

Part Number	Package Type	Identification Code
AP22802AW5-7	SOT25	XA
AP22802BW5-7	SOT25	XB

Package Outline Dimensions (All dimensions in mm.)

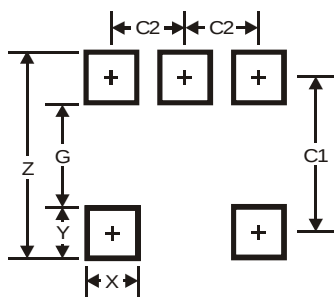
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SOT25			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
N	0.70	0.80	0.75
α	0°	8°	—
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version



Dimensions	Value (in mm)
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95

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